

Ch. 8 Homework Problems

JFET

[7]

$$V_{GS(off)} = -8V, I_{DSS} = 10mA, V_{GS} = 0 \text{ \& } V_{DS} > V_P \rightarrow I_D = ??$$

$$V_P = -V_{GS(off)} = 8V$$

$$\therefore \text{ at } V_{GS} = 0 \text{ and } V_{DS} > V_P \rightarrow I_D = I_{DSS}$$

$$\therefore I_D = 10mA$$

[9]

$$V_{GS(off)} = -4V, V_{DD} \uparrow \text{ until } I_D \text{ is steady state} \rightarrow V_{DS} = ??$$

$$\text{ as } V_{DD} \uparrow, V_{DS} \uparrow \text{ and } I_D \uparrow$$

$$\text{ when } V_{DS} = V_P = -V_{GS(off)} = 4V \rightsquigarrow I_D \text{ is saturated as } I_{DSS}$$

$$\therefore V_{DS} = 4V$$

[12]

$$g_{m0} = 3200\mu S, V_{GS(off)} = -8V, g_m = ?? \text{ at } V_{GS} = -4V$$

$$\therefore g_m = g_{m0} \left(1 - \frac{V_{GS}}{V_{GS(off)}} \right)$$

$$= 3200\mu \left[1 - \frac{-4}{-8} \right]$$

$$= 3200\mu \times 0.5$$

$$= 1600\mu S$$

[13]

$$V_{GS(off)} = -4V, g_{m0} = 2000\mu S, g_m \& g_{fs} = ?? \text{ at } V_{GS} = -2V$$

$$g_m = g_{m0} \left(1 - \frac{V_{GS}}{V_{GS(off)}} \right) = 2000 \left(1 - \frac{-2}{-4} \right)$$

$$\therefore g_m = 1428.6\mu S$$

$$g_{fs} = g_m = 1428.6\mu S$$

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(2)

a) $V_G = 0$
 $V_S = I_D R_S = 1\text{mA} \times 1\text{k}\Omega$
 $= 1\text{V}$

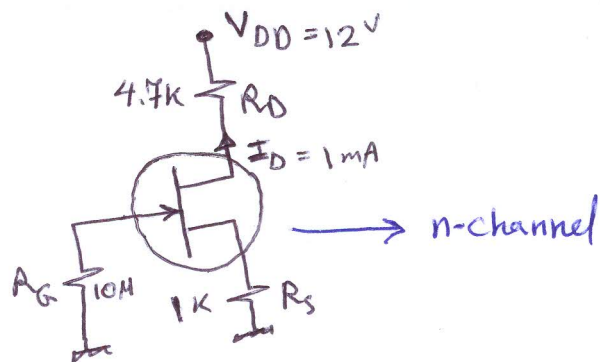
$\therefore V_{GS} = V_G - V_S = 0 - 1$

$\therefore \boxed{V_{GS} = -1\text{V}}$

$\therefore V_D = V_{DD} - I_D R_D = 12 - 1\text{mA} \times 4.7\text{k}\Omega = 7.3\text{V}$

$\therefore V_{DS} = V_D - V_S = 7.3 - 1$

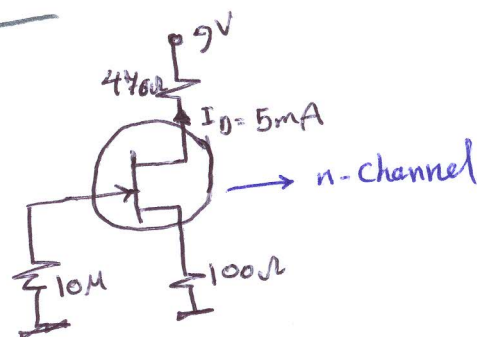
$\therefore \boxed{V_{DS} = 6.3\text{V}}$



b) $V_{GS} = V_G - V_S$
 $= -V_S = -I_D R_S$
 $= -5\text{mA} \times 100 = -5 \times 10^{-3} \times 100$
 $\therefore \boxed{V_{GS} = -0.5\text{V}}$

$V_{DS} = V_D - V_S$
 $= V_{DD} - I_D (R_D + R_S) = 9 - 5\text{mA} (470 + 100) = 9 - 2.85$

$\therefore \boxed{V_{DS} = 6.15\text{V}}$



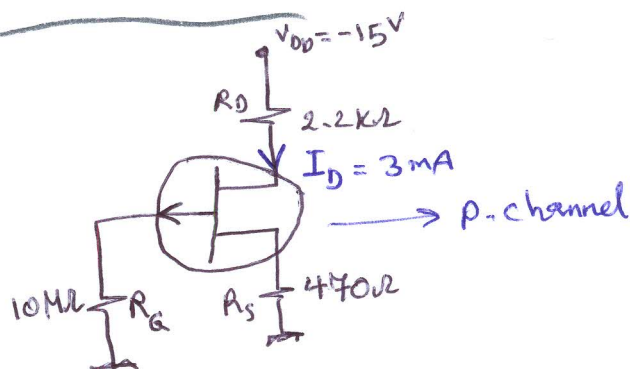
c) $V_G = 0$
 $V_S = -I_D R_S$
 $= -3 \times 10^{-3} \times 470$
 $= -1.41\text{V}$

$\therefore V_{GS} = V_G - V_S \therefore \boxed{V_{GS} = 1.41\text{V}}$

$V_D = V_{DD} + I_D R_D$
 $= -15 + 3\text{mA} \times 2.2\text{k}\Omega = -8.4\text{V}$

$\therefore V_{DS} = V_D - V_S$
 $= -8.4 + 1.41$

$\therefore \boxed{V_{DS} = -6.99\text{V}}$



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From the graph:

$$\text{at } I_D = 9.5 \text{ mA} \rightarrow V_{GS} \approx -2 \text{ V}$$

$$\therefore R_S = \left| \frac{V_{GS}}{I_D} \right| = \left| \frac{-2}{9.5 \text{ mA}} \right| \approx \underline{\underline{210.53 \, \Omega}}$$

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 $I_{DSS} = 14 \text{ mA}$, $V_{GS(off)} = -10 \text{ V}$, set up a midpoint bias for midpoint bias:

$$I_D = \frac{1}{2} I_{DSS} \Rightarrow \boxed{I_D = 7 \text{ mA}}$$

$$V_{GS} = \frac{V_{GS(off)}}{3.4} \Rightarrow \boxed{V_{GS} = -2.94 \text{ V}}$$

$$V_D = \frac{V_{DD}}{2} = \frac{24}{2} \Rightarrow V_D = 12 \text{ V}$$

$$\therefore V_{GS=0} \Rightarrow V_S = -V_{GS} = 2.94 \text{ V}$$

$$\therefore V_{DS} = V_D - V_S = 12 - 2.94 \Rightarrow \boxed{V_{DS} = 9.06 \text{ V}}$$

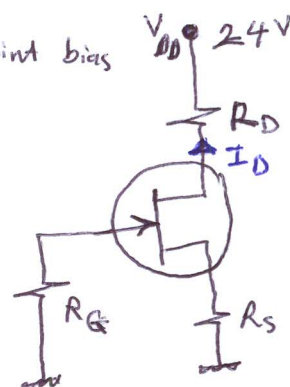
$$R_S = \left| \frac{V_{GS}}{I_D} \right| = \left| \frac{-2.94}{7 \text{ mA}} \right| \Rightarrow \boxed{R_S = 420 \, \Omega}$$

$$\therefore V_D = V_{DD} - I_D R_D \Rightarrow R_D = \frac{V_{DD} - V_D}{I_D} = \frac{24 - 12}{7 \text{ mA}}$$

$$\Rightarrow \boxed{R_D \approx 1.71 \text{ k}\Omega}$$

and R_G any large resistance

$$\text{Let } \boxed{R_G = 10 \text{ M}\Omega}$$



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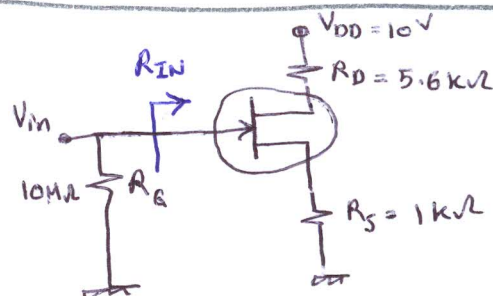
 $I_{DSS} = 20 \text{ nA}$ at $V_{GS} = -10 \text{ V}$

$$R_{IN(tot)} = R_G \parallel R_{IN}$$

$$\therefore R_{IN} = \left| \frac{V_{GS}}{I_{DSS}} \right| = \left| \frac{-10}{20 \text{ nA}} \right| = 0.5 \text{ G}\Omega$$

$$\text{or } R_{in} = 500 \text{ M}\Omega$$

$$\therefore R_{IN(tot)} = 10 \text{ M}\Omega \parallel 500 \text{ M}\Omega = \frac{10 \times 500}{10 + 500}$$



$$\Rightarrow \boxed{R_{IN(tot)} \approx 9.8 \text{ M}\Omega}$$

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$$\therefore V_G = 0, V_S = -I_D R_S$$

$$\therefore V_{GS} = +I_D R_S$$

$$\text{at } I_D = 0$$

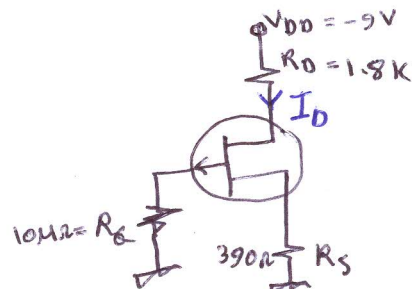
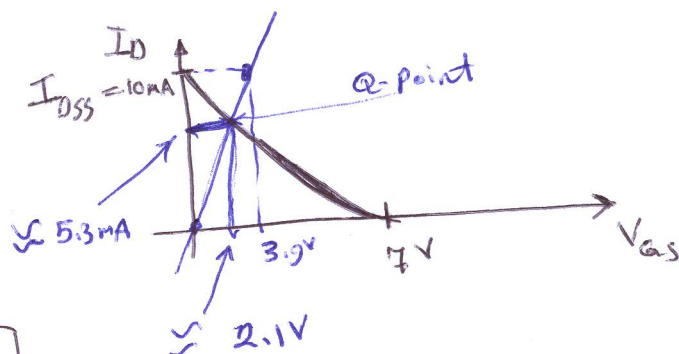
$$\therefore V_{GS} = 0 * (390) = 0$$

$$\text{at } I_D = I_{DSS} = 10 \text{ mA}$$

$$V_{GS} = 10 \text{ mA} (390 \Omega) = 3.9 \text{ V}$$

\therefore the Q-point is: (from graph)

$$V_{GS} \approx 2.1 \text{ V} \text{ and } I_D \approx 5.3 \text{ mA}$$



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$V_D = 5 \text{ V}$, determine the Q-point??

$\rightarrow I_D \text{ and } V_{GS}??$

$$\therefore V_D = V_{DD} - I_D R_D$$

$$\therefore I_D = \frac{V_{DD} - V_D}{R_D} = \frac{9 - 5}{4.7 \text{ k}}$$

$$\therefore I_D \approx 0.851 \text{ mA}$$

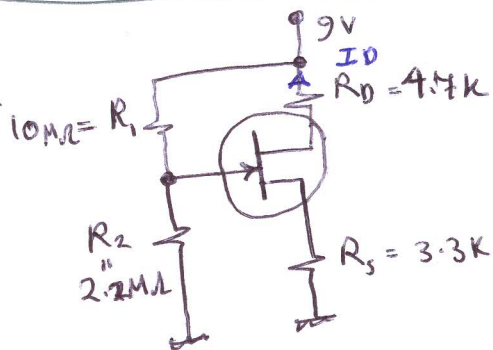
$$V_G = V_{DD} \left(\frac{R_2}{R_1 + R_2} \right) = 9 \left(\frac{2.2}{12.2} \right) \therefore V_G \approx 1.623 \text{ V}$$

$$V_S = I_D R_S = (0.851 \text{ mA}) * (3.3 \text{ k}\Omega) \therefore V_S \approx 2.81 \text{ V}$$

$$\therefore V_{GS} = V_G - V_S = 1.623 - 2.81 \therefore V_{GS} \approx -1.184 \text{ V}$$

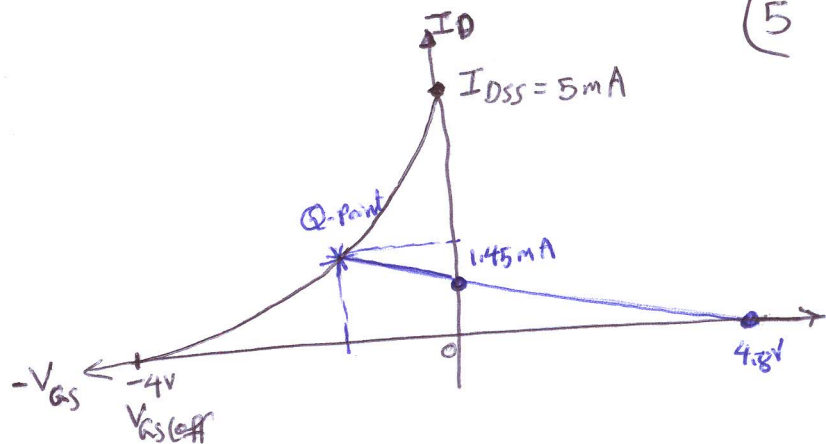
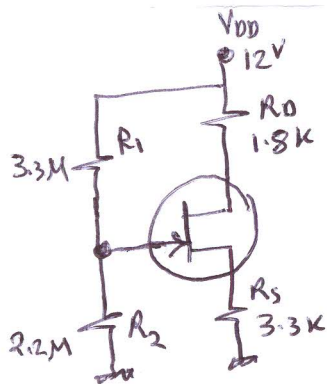
\therefore the Q-point is:

$$V_{GS} = -1.184 \text{ V} \text{ and } I_D = 0.851 \text{ mA}$$



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Find Q-Point ??



$$V_G = \left(\frac{R_2}{R_1 + R_2} \right) V_{DD} = \frac{2.2}{3.3 + 2.2} (12) = 4.8V$$

$$V_S = I_D R_S$$

at $I_D = 0$: $V_S = 0$, $V_G = 4.8$ $\therefore V_{GS} = 4.8V$

at $V_{GS} = 0$: $0 = 4.8 - I_D R_S \therefore I_D = \frac{4.8}{R_S} \approx 1.45 \text{ mA}$

\therefore the Q-point is : (from graph)

$$V_{GS} \approx -1.4V \text{ \& } I_D \approx 2 \text{ mA}$$

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$V_{DS1} = 0.4 \rightarrow I_{D1} = 0.15 \text{ mA}$, $V_{DS2} = 0.6V \rightarrow I_{D2} = 0.45 \text{ mA}$;
range of R_{DS} values ??

$$\therefore R_{DS} = \frac{V_{DS}}{I_D}$$

$$\therefore R_{DS1} = \frac{0.4}{0.15 \text{ mA}} \approx 2.67 \text{ k}\Omega$$

$$R_{DS2} = \frac{0.6}{0.45 \text{ mA}} \approx 1.33 \text{ k}\Omega$$

\therefore the range of R_{DS} values : $1.33 < R < 2.67 \text{ (k}\Omega\text{)}$

and

$$\Delta R_{DS} = R_{DS2} - R_{DS1} = -1.34 \text{ k}\Omega$$

i.e. decreases by $1.34 \text{ k}\Omega$

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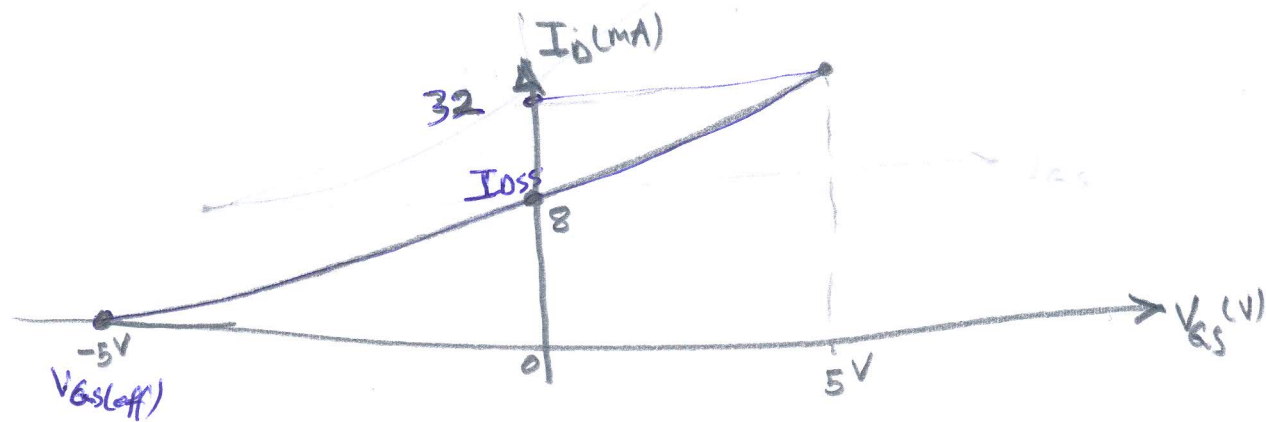
$$V_{GS(off)} = -5V, I_{DSS} = 8mA$$

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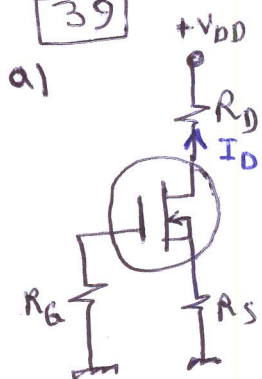
a) as $V_{GS(off)}$ is -ve \therefore it is a n-channel MOSFET

b)
$$I_D = I_{DSS} \left(1 - \frac{V_{GS}}{V_{GS(off)}}\right)^2$$

$V_{GS}(V)$	-5	-4	-3	-2	-1	0	1	2	3	4	5
$I_D(mA)$	0	0.32	1.28	2.88	5.12	8	11.52	15.68	20.48	25.92	32



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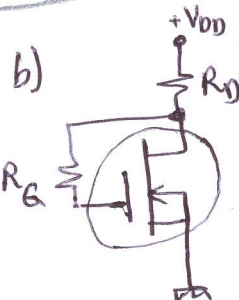
$$V_G = 0 \text{ as } I_G = 0$$

$$V_S = I_D R_S$$

$$\therefore V_{GS} = -I_D R_S \text{ (-ve)}$$

\therefore DMOSFET is n-channel

depletion



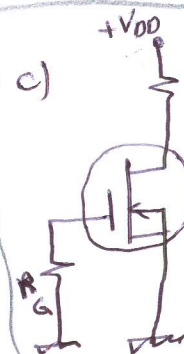
$$V_{GS} = V_{DS} \text{ as } I_G = 0$$

$$\therefore V_{DS} = V_{DD} - I_D R_D > 0$$

$\therefore V_{GS}$ is +ve
and

DMOSFET is n-channel

Enhancement mode



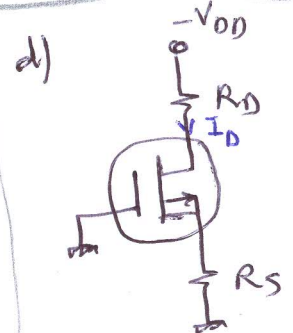
$$V_G = 0 \text{ as } I_G = 0$$

$$V_S = 0$$

$$\therefore V_{GS} = 0$$

neither depletion
nor enhancement
mode

it is zero biased



$$V_G = 0$$

$$V_S = -I_D R_S$$

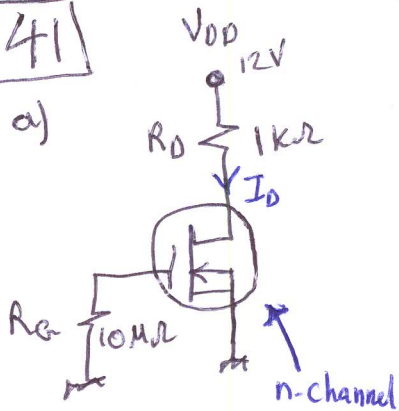
$$\therefore V_{GS} = I_D R_S > 0$$

$\therefore V_{GS}$ is +ve
and

DMOSFET is p-channel

depletion mode

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$$\therefore V_{GS} = 0 \text{ as } I_G = 0$$

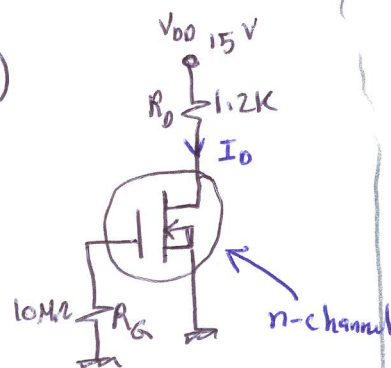
$$\therefore I_D = I_{DSS} = 8 \text{ mA}$$

$$\therefore V_{DS} = V_{DD} - I_D R_S$$

$$= 12 - (8 \text{ mA})(1 \text{ k}\Omega)$$

$$\therefore \boxed{V_{DS} = 4 \text{ V}}$$

b)



$$V_{GS} = 0$$

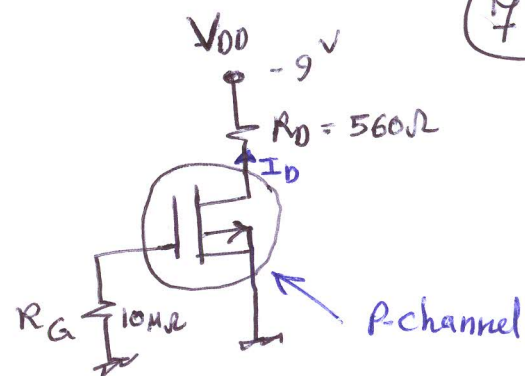
$$\therefore I_D = I_{DSS} = 8 \text{ mA}$$

$$\therefore V_{DS} = 15 - (8 \text{ mA})(1.2 \text{ k}\Omega)$$

$$= 15 - 9.6$$

$$\therefore \boxed{V_{DS} = 5.4 \text{ V}}$$

c)



$$V_{GS} = 0, I_D = I_{DS} = 8 \text{ mA}$$

$$\therefore V_{DS} = V_{DD} + I_D R_S$$

$$= -9 + (8 \text{ mA})(560 \Omega)$$

$$= -9 + (8 \times 10^{-3} \times 560)$$

$$= -9 + 4.48$$

$$\therefore \boxed{V_{DS} = -4.52 \text{ V}}$$

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a) $I_{D(on)} = 3 \text{ mA}$ at $V_{GS} = 4 \text{ V}$

$$V_{GS(th)} = 2 \text{ V}, V_{GS}, V_{DS} = ???$$

$$V_{GS} = V_{DD} \left(\frac{R_2}{R_1 + R_2} \right)$$

$$= 10 \left[\frac{4.7 \text{ M}}{14.4 \text{ M}} \right]$$

$$\therefore \boxed{V_{GS} \approx 3.194 \text{ V}}$$

$$\therefore I_D = K (V_{GS} - V_{GS(th)})^2$$

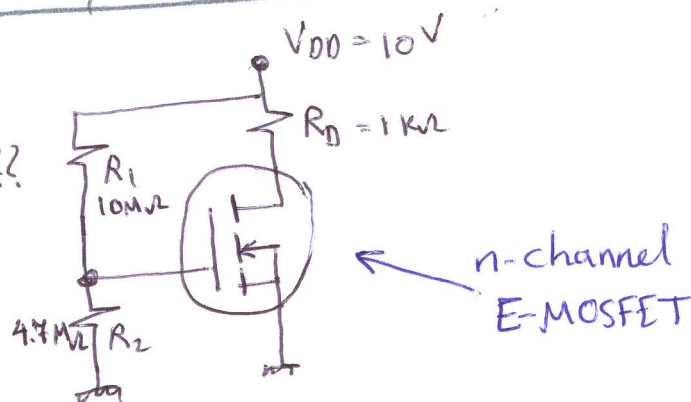
$$\therefore K = \frac{I_{D(on)}}{(V_{GS} - V_{GS(th)})^2} = \frac{3 \text{ mA}}{(4 - 2)^2} = 0.75 \text{ mA/V}^2$$

$$\therefore \text{at } V_{GS} = 3.194 \text{ V}:$$

$$I_D = 0.75 (3.194 - 2)^2 = 1.045 \text{ mA}$$

$$\therefore V_{DS} = V_{DD} - I_D R_D = 10 - (1.045 \text{ mA})(1 \text{ k}\Omega)$$

$$\therefore \boxed{V_{DS} = 8.925 \text{ V}}$$



42) $I_{D(on)} = 2 \text{ mA}$ at $V_{GS} = 3 \text{ V}$
 $V_{GS(th)} = 1.5 \text{ V}$

$$\therefore V_{GS} = \left(\frac{R_2}{R_1 + R_2} \right) V_{DD}$$

$$= \left(\frac{10 \text{ M}}{10 \text{ M} + 10 \text{ M}} \right) 5 = \frac{1}{2} \times 5$$

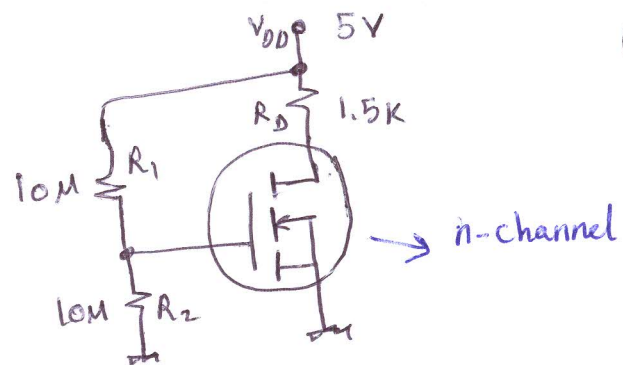
$$\therefore V_{GS} = 2.5 \text{ V}$$

$$K = \frac{I_{D(on)}}{(V_{GS} - V_{GS(th)})^2} = \frac{2 \text{ m}}{(3 - 1.5)^2} \approx 0.89 \text{ mA/V}^2$$

$$\therefore I_D = 0.89 (2.5 - 1.5)^2 = 0.89 \text{ mA}$$

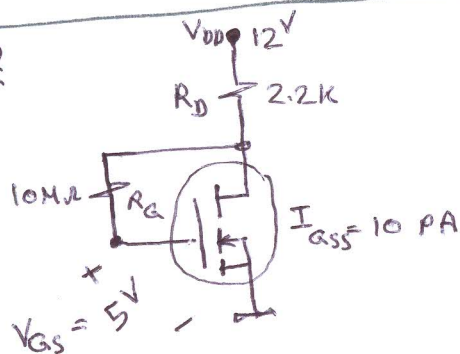
$$\therefore V_{DS} = V_{DD} - I_D R_D = 5 - 0.89 \text{ m} \times 1.5 \text{ K}$$

$$\therefore V_{DS} = 3.665 \text{ V}$$



43) $I_D, V_{DS} ??$

a)



$$\therefore V_{GS} = V_{DS} - I_{GSS} R_G$$

$$\therefore V_{DS} = 5 + (10 \times 10^{-12}) (10 \times 10^6) = 5 + 10^{-4}$$

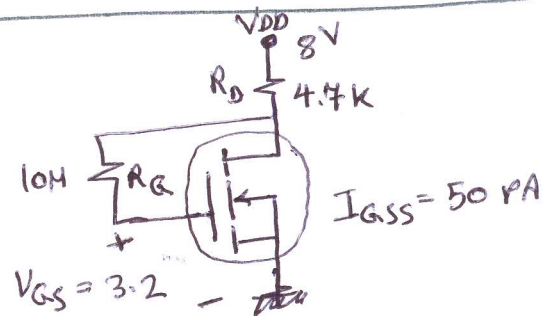
$$\therefore V_{DS} = 5.0001 \text{ V}$$

$$\therefore V_{DS} = V_{DD} - I_D R_D$$

$$\therefore I_D = \frac{V_{DD} - V_{DS}}{R_D} = \frac{12 - 5.0001}{2.2 \text{ K}}$$

$$\therefore I_D \approx 3.182 \text{ mA}$$

b)



$$\begin{aligned} V_{DS} &= V_{GS} + I_{GSS} R_G \\ &= 3.2 + (50 \times 10^{-12}) (10 \times 10^6) \\ &= 3.2 + 5 \times 10^{-4} \end{aligned}$$

$$\therefore V_{DS} = 3.2005 \text{ V}$$

$$I_D = \frac{V_{DD} - V_{DS}}{R_D} = \frac{8 - 3.2005}{4.7 \text{ K}}$$

$$\therefore I_D \approx 1.02 \text{ mA}$$